

EV318283946



Inventor: **Cem Basc ri**  
Title: **Methods of Forming Capacitor Constructions Comprising Perovskite-Type Dielectric Materials With Different Amount of Crystallinity Regions**

Assignee: **Micron Technology, Inc.**

Serial No.: **09/932,003**

Filed: **August 17, 2001**

**SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT**

**PURSUANT TO 37 C.F.R. §§ 1.56, 1.97 AND 1.98**

In compliance with 37 C.F.R. §§ 1.56, 1.97 and 1.98, the Examiner's attention is directed to the reference listed on the attached Form PTO-1449 and a copy of which is attached. No admission is made regarding whether the submitted reference is prior art.

Citation of this reference is respectfully requested.

Respectfully submitted,

Date: 9/2/03

Attorney: [Signature]

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TECHNOLOGY CENTER 2800

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Form PTO-1449 		U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE		ATTY. DOCKET NO. M122-1731		SERIAL NO. 09/932,003	
LIST OF ART CITED BY APPLICANT (Use several sheets if necessary)				APPLICANT Cem Basceri		FILING DATE August 17, 2001	
				GROUP 2813			

U.S. PATENT DOCUMENTS							
*Examiner Initial	Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate	
	AA	6,372,686 B1	04/02	Golden			
	AB						
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						Yes	No
	AM						
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OTHER REFERENCES (including Author, Title, Date, Pertinent Pages, Etc.)			
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EXAMINER	DATE CONSIDERED
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\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.